# **RF5375**



#### **Absolute Maximum Ratings**

<u> </u>		
Parameter	Rating	Unit
Supply Voltage	-0.5 to +5.4	V <sub>DC</sub>
PA Regulated Voltage (V <sub>REG</sub> )	-0.5 to 3.5	V <sub>DC</sub>
DC Supply Current	500	mA
Maximum TX and RX Input Power (no damage)	0	dBm
Operating Case Temperature	-40 to +85	°C
Storage Temperature	-40 to +150	°C
Moisture Sensitivity	MSL2	



#### Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

RoHS status based on EUDirective 2002/95/EC (at time of this document revision).

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Dayamatay	Specification		I I to i t	Condition		
Parameter	Min.	Тур.	Max.	Unit	Condition	
Compliance					IEEE802.11b/g/n Standards; FCC CFG 15.247, .205, .209; EN and JDEC.	
Operating Conditions					$\label{eq:VCC} $V_{\text{CC}}$=3.0V to 4.8V; $V_{\text{REG}}$=2.8V to 2.9V; $\text{Switch Control}$ \\ \text{voltage}$=2.7V to 3.6V; $\text{Temp}$=-10 °C to +70 °C (Spec Complant); $\text{Temp}$=-40 °C to \\ -10 °C and +70 °C to +85 °C (Reduced Performance); $\text{Unless noted otherwise}$ $	
Frequency Range	2.4		2.5	GHz		
Power Supply	3.0	3.3	4.8	V		
	2.7			V	Derated performance	
V <sub>REG</sub> Voltage						
ON	2.80	2.85	2.90	V	PA in "ON" state	
OFF	0		0.2	V	PA in "OFF" state	
Output Power						
11n	16.5	17		dBm	V <sub>CC</sub> ≥3.0V OFDM 54Mbps	
11n	17.5	18		dBm	V <sub>CC</sub> ≥3.3V OFDM 54Mbps	
11g	18	18.5		dBm	V <sub>CC</sub> ≥3.3V OFDM 54Mbps	
11b	19.5	21		dBm	11Mbps, CCK, V <sub>CC</sub> ≥3.3V	
EVM						
11g			4	%	18dBm, OFDM 54Mbps, V <sub>CC</sub> =3.3V to 4.8V, all temperature	
11n		2.5	3.0	%	17.5dBm, OFDM 54Mbps, V <sub>CC</sub> =3.3V to 4.8V, all temperature	
			3.0	%	16.5dBm, OFDM 54Mbps, V <sub>CC</sub> = 3.0 V <sub>DC</sub> , all temperature	
Adjacent Channel Power					P <sub>OUT</sub> =21Bm, Vcc=3.3v, 11Mbps CCK signal. See note 2	
ACP1		-36	-33	dBc	+/- 11MHz Offset from carrier	
ACP2		-56	-52	dBc	+/- 22MHz Offset from carrier	
Gain	23	25	29	dB	At rated P <sub>OUT</sub>	
Gain Variance Slope						
Channel 40 MHz BW	-1.0		+1.0	dB		
Channel 20 MHz BW	-0.5		+0.5	dB		
Frequency 100 MHz BW	-2		+2	dB	In-Band variance 2.4 GHz to 2.5 GHz	
Out of Band Rejection						
2170MHz	6	8		dBc	CW Signal	



Davanastav	Specification			11.2	O andition	
Parameter	Min.	Тур.	Max.	Unit	Condition	
Compliance, cont.	_					
Power Detector						
Output Power Range	0		23	dBm		
Voltage Range	0.1		1.5	V <sub>DC</sub>		
Voltage at POUT=18dBm	0.6	0.65	0.7	dB	11g; 50Ω; V <sub>CC</sub> =3.0V to 4.8 V	
Filter Bandwidth		0.1		MHz	**	
Sensitivity						
P <sub>OUT</sub> <.5V	10			mV/dB		
P <sub>OUT</sub> >.5V	20			mV/dB		
Voltage Target at 23 dBm P <sub>OUT</sub>		1.2		V	Vcc=3.3v, Temp=25°C	
Load Variation			±200	mV	up to 3:1 VSWR	
Current Consumption					ap to 6.2 16111	
Quiescent		135	180	mA	V <sub>CC</sub> =3.0V to 4.8V, All Temp	
Operating		170	200	mA	$V_{CC} \le 4.2 V_{DC}$ , $P_{OUT} = 18 dBm$ , 11n, 50Ω, Temp=25°C	
Operating			220	mA	$V_{CC} \le 4.8 V_{DC}$ , $P_{OLIT} = 17.5 dBm$ , $11n$ , $50\Omega$ , All Temp	
Operating		210	270	mA	$V_{CC} \le 4.2 V_{DC}$ , $P_{OUT} = 21 dBm$ , $11b$ , $50 \Omega$ , All Temp	
		3	5	mA	T=25 °C	
V <sub>REG</sub>		3	500	nA	·	
FEM Leakage					V <sub>CC</sub> ="0N", V <sub>REG</sub> =0.2V <sub>DC</sub> , RF OFF	
V <sub>REG</sub> Leakage			50	nA		
Noise Figure		8	9	dB		
Input Return Loss	8	10		dB		
Thermal Resistance		52		°C/W	V <sub>CC</sub> =4.8V, V <sub>REG</sub> =2.95V, C_TX=3.3, C_RX=C_BT=GND, P <sub>OUT</sub> =18dBm, Modulation=OFDM 11g, Freq=2.45GHz, DC=100%, T=85 °C	
Harmonics					P <sub>OUT</sub> =21dBm, 1Mbps, CCK BW=1MHz, up to 3:1 load	
Second			-15	dBm	4.80GHz to 5.00GHz, V <sub>CC</sub> =3.3V, Temp=25 °C	
Third			-20	dBm	7.20GHz to 7.50GHz, V <sub>CC</sub> =3.3V, Temp=25 °C	
Stability				u2	PA must be stable from 0 dBm to 21dBm. CW Signal, No	
Stability					spurs above -41.25dBm for non-harmonic related signals.	
Output VSWR	4:1				All phase angles, no spurious or oscillations.	
Ruggedness					No Damage Conditions over Voltage and Temperature	
Output VSWR	10:1					
Input Power			0	dBm	CW Input Power	
Input Port Impedance		50		Ω		
Turn-On/Off Time			1	usec	Output stable to within 90% of final gain	
2.4 GHz Receive						
Frequency	2.4		2.5	GHz		
Insertion Loss		.08	1.2	dB		
Input P1dB	22			dBm		
Passband Ripple						
WiFi RX Mode	-0.2		+0.2	dB		
WiFi RX/BT Mode	-0.2		+0.2	dB		
WiFi RX Port Return Loss	10	12		dB		
WiFi RX Port Impedance		50		Ω		

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Parameter	Specification			11:4	Condition	
Farameter	Min.	Тур.	Max.	Unit	Condition	
Bluetooth®						
Frequency	2.4		2.5	GHz		
Insertion Loss		0.8	1.2	dB		
Bluetooth Input P1dB	22			dBm		
Bluetooth Port Return Loss	10	12		dB		
Bluetooth Port Impedance		50		Ω		
Other Requirements						
Antenna Port Impedance		50		Ω		
Return Loss	10	12		dB	In WiFi RX or BT Mode	
Isolation						
ANT to RX	20			dB	At rated P <sub>OUT</sub> in TX Mode	
Switch Control Voltage						
Low	0		0.2	V		
High	2.7		3.6	V		
Switch Control Current						
Low			0.5	uA		
High			100	uA		
ESD						
Human Body Model	1000			V	Pin-Ground	
Charge Device Model	500			V	JESD22-C101C. Class III	
Case Temperature	-10		+70	°C	Full Performance	
Extreme Case Temperature	-40		+85	°C	Reduced Performance	

Note 1: The PA must operate with gated bias voltage input at 1% to 99% duty cycle.

Note 2: The output power for channels 1 and 11 may be reduced to meet FCC restricted band requirements.

#### **Switch Control Logic Truth Table**

Mode	C_TX	C_RX	C_BT	VREG
Transmit	High	Low	Low	High
Receive	Low	High	Low	Low
Bluetooth	Low	Low	High	Low
Simultaneous	Low	High	High	Low



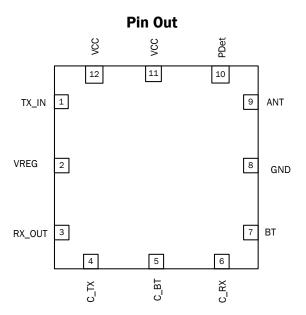


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Pin	Function	Description
1	TX IN	RF input for the 802.11b/g/n PA. Input is matched to $50\Omega$ . DC block required.
2	VREG	Regulated voltage for the PA bias control circuit. An external bypass capacitor may be needed on the VREG line for decoupling purposes.
3	RX OUT	Receive port for 802.11b/g/n band. Internally matched to $50\Omega$ . DC block required.
4	C_TX	Control pin for WiFi Transmit Port. See truth table for proper settings.
5	C_BT	Control pin for Bluetooth® Port. See truth table for proper settings.
6	C_RX	Control pin for WiFi Receive Port. See truth table for proper settings.
7	BT PORT	Bluetooth® RF Port. DC block required.
8	GND	Ground connection.
9	ANT	Antenna port matched to $50\Omega$ . DC block required.
10	POWER DETECT	Power detector voltage for TX section. P <sub>DET</sub> voltage varies with output power. May need external decoupling.
11	VCC	Supply voltage for the FEM. See applications schematic for biasing and bypassing components.
12	VCC	Same as pin 11.
Pkg Base	GND	Ground connection. The backside of the package should be connected to the ground plane through a short path, i.e., PCB vias under the device are recommended.

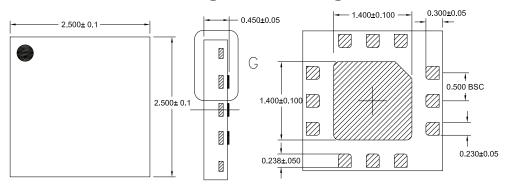
# **RF5375**

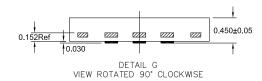






# **Package Outline Drawing**

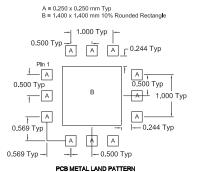




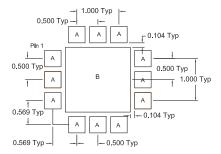
- 1) PIN 1 INDICATOR SHADED AREA
- 2) CHAMFERRED AREA IS PIN 1 INDICATOR



#### **PCB Recommendations**

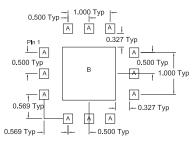


A = 0.390 x 0.390 mm Typ B = 1.540 x 1.540 mm 10% Rounded Rectangle



#### PCB SOLDER MASK LAND PATTERN

A = 0.225 x 0.225 mm Typ B = 1.260 x 1.260 mm 10% Rounded Rectangle



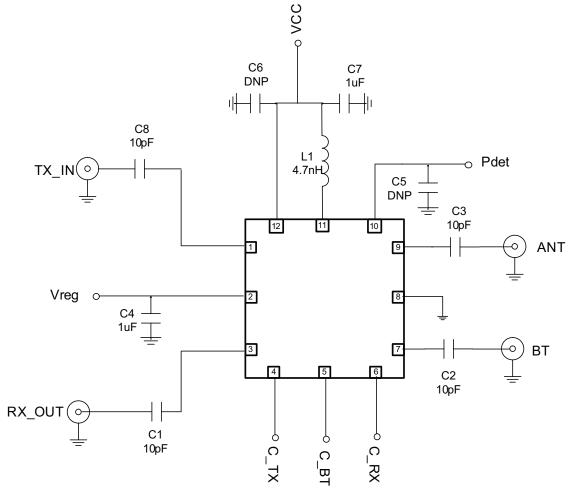
PCB STENCIL PATTERN

PCB land patterns for RFMD components are based on IPC-7351 standards and RFMD empirical data. The pad pattern shown has been developed and tested for optimized assembly at RFMD. The PCB land pattern has been developed to accommodate lead and package tolerances. Since surface mount processes vary from company to company, careful process development is recommended.

Thermal vias for center slug "B" should be incorporated into the PCB design. The number and size of thermal vias will depend on the application. Example of the number and size of vias can be found on the RFMD evaluation board layout.



## **Evaluation Board Schematic**



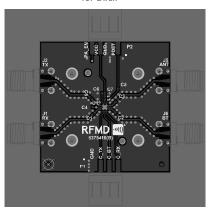
Note: Components C5 and C6 may not be needed in the final schematic. This will be dependent on board layout and noise coupling to these pins. TX input connects directly to the transceiver. If no DC is present on this pin, C8 may also be eliminated.



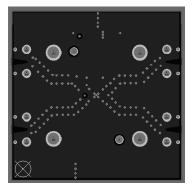
## **Evaluation Board Layout**

Note: For best performance, it is recommended to follow the routing and grounding of the RFMD evaluation board as close as possible. At a minimum, use five ground thermal vias on the package center slug (via size: 12 mil hole by 22 mil capture pad).

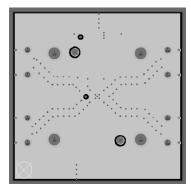
TOP LAYER



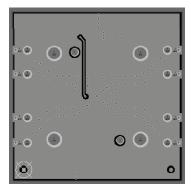
MID LAYER-1



MID LAYER-2

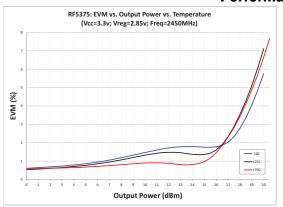


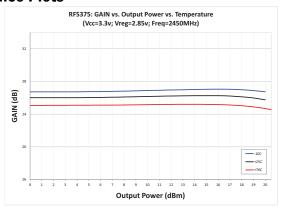
**BOTTOM LAYER** 

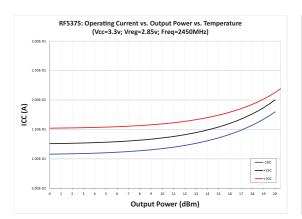


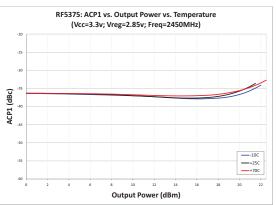


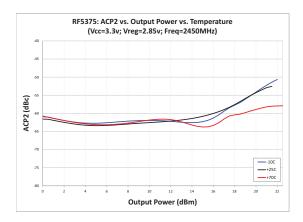
## **Performance Plots**

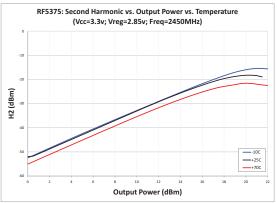






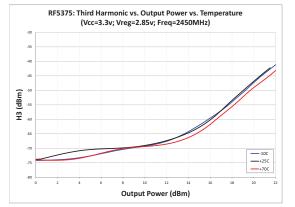


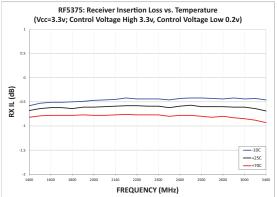


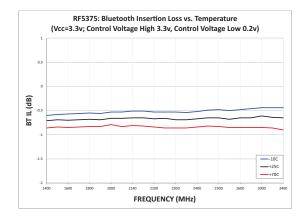




## **Performance Plots**







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